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**FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16667**

Generic Copy

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**Issue Date:** 24-Jun-2011

**TITLE:** Wire Size Change in SC88 Package on Gate Pad for MOSFET Products

**PROPOSED FIRST SHIP DATE:** 01-Oct-2011

**AFFECTED CHANGE CATEGORY(S):** ON Semiconductor SC88 Assembly – Wire Bond

**FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:**

Contact your local ON Semiconductor Sales Office or Jason Jeong <[Jason.Jeong@onsemi.com](mailto:Jason.Jeong@onsemi.com)>

**SAMPLES:** Contact your local ON Semiconductor Sales Office or Jason Jeong  
<[Jason.Jeong@onsemi.com](mailto:Jason.Jeong@onsemi.com)>

**ADDITIONAL RELIABILITY DATA:** Available

Contact your local ON Semiconductor Sales Office or Donna Scheuch <[d.scheuch@onsemi.com](mailto:d.scheuch@onsemi.com)>

**NOTIFICATION TYPE:**

Final Product/Process Change Notification (FPCN)

Final change notification sent to customers. FPCNs are issued at least 90 days prior to implementation of the change.

ON Semiconductor will consider this change approved unless specific conditions of acceptance are provided in writing within 30 days of receipt of this notice. To do so, contact <[quality@onsemi.com](mailto:quality@onsemi.com)>.

**DESCRIPTION AND PURPOSE:**

ON Semiconductor is notifying customers of its use of 0.8mil wire in place of 2mil wire on gate pad for their SC88 Packaged Products assembled with MOSFET Die. This change is being done to optimize the gate wire of the package to align to device requirements.

Reliability Qualification and full electrical characterization over temperature has been performed.

**FINAL PRODUCT/PROCESS CHANGE NOTIFICATION #16667****RELIABILITY DATA SUMMARY:****Reliability Test Results:**

Device Name: NTJS3157NT1G

Test: High Temperature Gate Bias (HTGB)

Conditions: Ta = 150°C, Vgs = 100% Max Rated Vgs, Duration : 1008-Hrs, 3-Lots

Results: 0/252

Test: Temperature Cycling (TC-PC)

Conditions: Ta = -65°C/150°C, Air-to-Air, Dwell ≥ 10-min, 1000-cycles, 3-Lot

Results: 0/252

Test: Intermittent Operating Life (IOL-PC)

Conditions: Ta = 25°C, Delta Tj = 100°C, 2-min on/off, 15K- cycle, 3-Lot

Results: 0/252

**ELECTRICAL CHARACTERISTIC SUMMARY:**

There is no change in electrical parametric performance. Characterization data is available upon request.

**CHANGED PART IDENTIFICATION:**

There will be no physical change with products assembled with 0.8mil wire in place of 2mil wire. Products (listed on this FPCN) assembled with 0.8mil wire from the ON Semiconductor facility in Leshan, China will have a Finish Good Date Code representing Work Week 40, 2011 or newer.

**List of affected General Parts:**

NTJS3151PT1G

NTJS3151PT2G

NTJS3157NT1

NTJS3157NT1G

NTJS3157NT2G

NTJS4151PT1G

NTJS4160NT1G